

SEMITOP® 3

IGBT Module

SK50MLI066

Target Data

Features

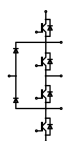
- Compact design
- One screw mounting
- Heat transfer and isolation through direct copper bonded aluminium oxide ceramic (DCB)
- Trench IGBT technology
- CAL technology FWD

Typical Applications*

- 3 Level Inverter
- UPS

Remarks

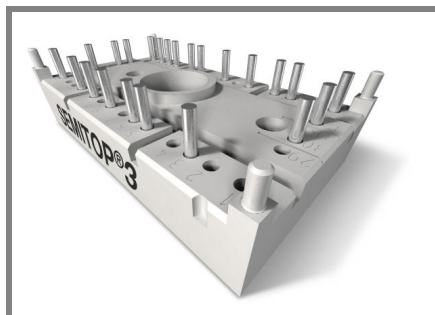
- Visol = 3000V AC, 1s, 50Hz
- Dynamic measure: DUT= IGBT (Gate pin 1) and Neutral Clamp Diode (Kathode pin 16) as free-wheeling diode



MLI

Absolute Maximum Ratings		T _s = 25 °C, unless otherwise specified	
Symbol	Conditions	Values	Units
IGBT			
V _{CES}	T _j = 25 °C	600	V
I _C	T _j = 175 °C T _s = 25 °C T _s = 70 °C	60 50	A A
I _{CRM}	I _{CRM} = 2 x I _{Cnom}	100	A
V _{GES}		± 20	V
t _{psc}	V _{CC} = 360 V; V _{GE} ≤ 20 V; T _j = 150 °C V _{CES} < 600 V	6	μs
Inverse Diode			
I _F	T _j = 175 °C T _s = 25 °C T _s = 70 °C	56 44	A A
I _{FRM}	I _{FRM} = 2 x I _{Fnom}	100	A
I _{FSM}	t _p = 10 ms; half sine wave T _j = 150 °C	320	A
Freewheeling Diode			
I _F	T _j = 175 °C T _s = 25 °C T _s = 70 °C	56 44	A A
I _{FRM}	I _{FRM} = 2 x I _{Fnom}	60	A
I _{FSM}	t _p = 10 ms; half sine wave T _j = 150 °C	320	A
Module			
I _{t(RMS)}			A
T _{vj}		-40 ... +175	°C
T _{stg}		-40 ... +125	°C
V _{isol}	AC, 1 min.	2500	V

Characteristics		$T_s = 25^\circ\text{C}$, unless otherwise specified			
Symbol	Conditions	min.	typ.	max.	Units
IGBT					
$V_{GE(th)}$	$V_{GE} = V_{CE}, I_C = 0,8\text{ mA}$	5	5,8	6,5	V
I_{CES}	$V_{GE} = 0\text{ V}, V_{CE} = V_{CES} \quad T_j = 25^\circ\text{C}$			0,0026	mA
I_{GES}	$V_{CE} = 0\text{ V}, V_{GE} = 20\text{ V} \quad T_j = 25^\circ\text{C}$			600	nA
V_{CE0}			$T_j = 25^\circ\text{C}$	0,9	V
			$T_j = 150^\circ\text{C}$	0,8	V
r_{CE}	$V_{GE} = 15\text{ V}$		$T_j = 25^\circ\text{C}$	11	$\text{m}\Omega$
			$T_j = 150^\circ\text{C}$	17	$\text{m}\Omega$
$V_{CE(sat)}$	$I_{Cnom} = 50\text{ A}, V_{GE} = 15\text{ V}$		$T_j = 25^\circ\text{C}_{chiplev.}$	1,45	V
			$T_j = 150^\circ\text{C}_{chiplev.}$	1,65	V
C_{ies}	$V_{CE} = 25, V_{GE} = 0\text{ V} \quad f = 1\text{ MHz}$		3,1		nF
C_{oes}			0,2		nF
C_{res}			0,093		nF
$t_{d(on)}$	$R_{Gon} = 16\ \Omega$	$V_{CC} = 300\text{ V}$ $I_C = 50\text{ A}$	30		ns
t_r			31		ns
E_{on}	$R_{Goff} = 16\ \Omega$	$T_j = 150^\circ\text{C}$ $V_{GE} = -7/+15\text{ V}$	1,46		mJ
$t_{d(off)}$			351		ns
t_f			45		ns
E_{off}	per IGBT		2,02		mJ
$R_{th(j-s)}$			1,11		K/W



SEMITOP® 3

IGBT Module

SK50MLI066

Target Data

Features

- Compact design
- One screw mounting
- Heat transfer and isolation through direct copper bonded aluminium oxide ceramic (DCB)
- Trench IGBT technology
- CAL technology FWD

Typical Applications*

- 3 Level Inverter
- UPS

Remarks

- Visol = 3000V AC, 1s, 50Hz
- Dynamic measure: DUT= IGBT (Gate pin 1) and Neutral Clamp Diode (Kathode pin 16) as free-wheeling diode

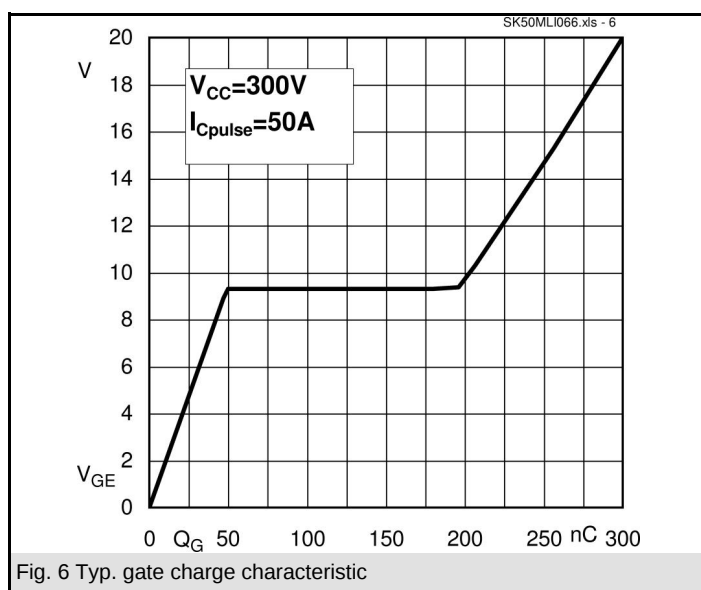
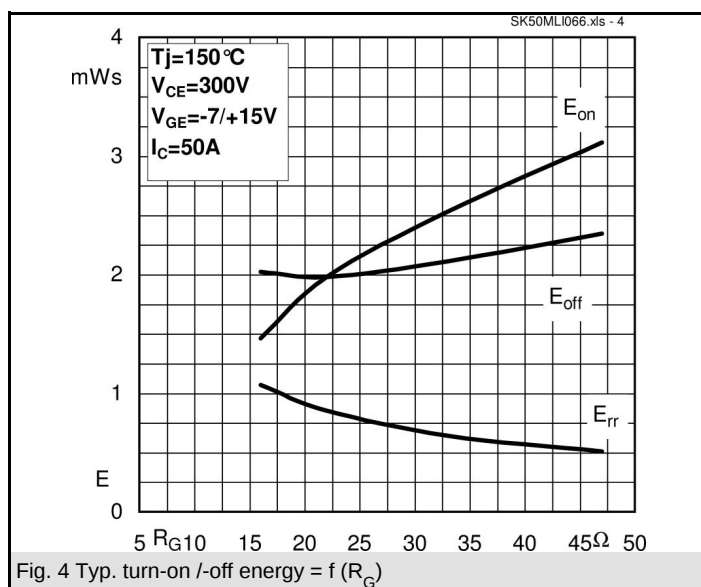
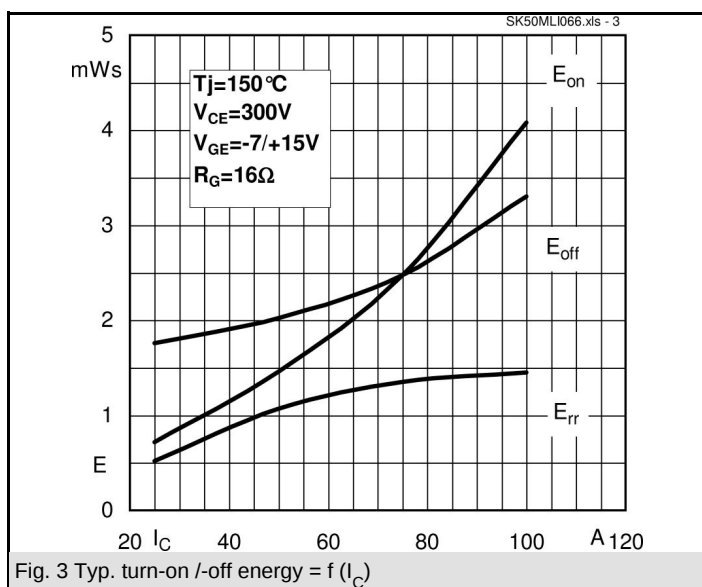
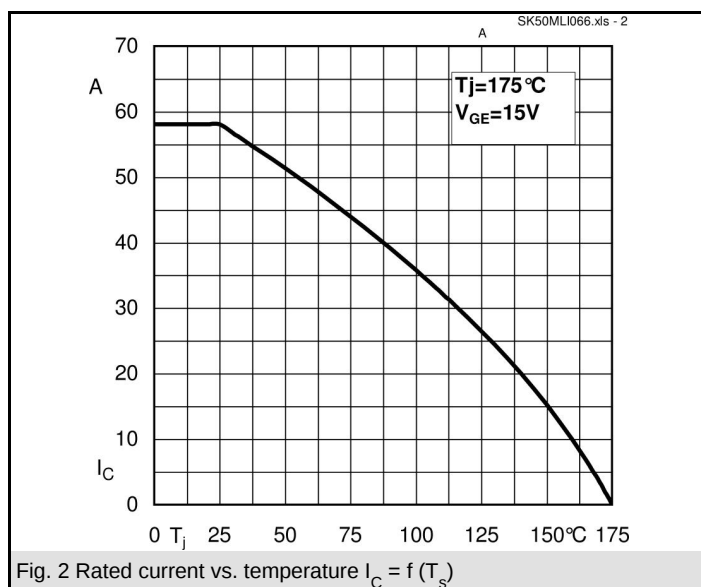
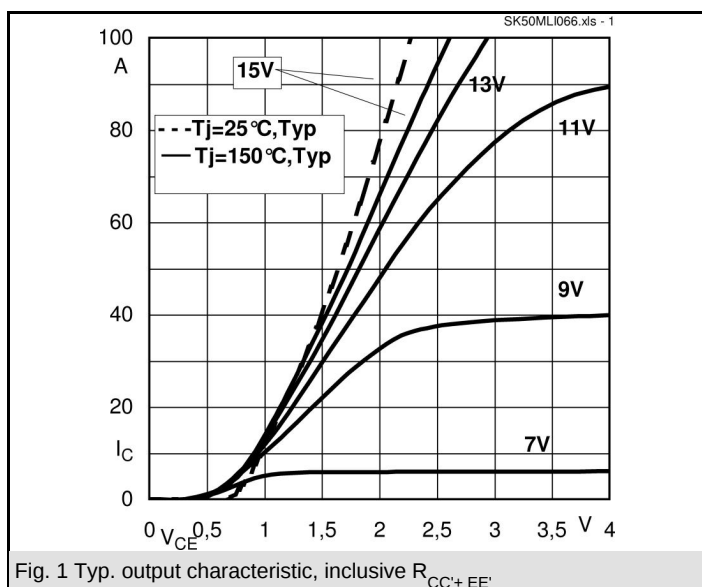
Characteristics						
Symbol	Conditions		min.	typ.	max.	Units
Inverse Diode (Antiparallel Diode)						
V _F = V _{EC}	I _{Fnom} = 50 A; V _{GE} = 0 V	T _j = 25 °C _{chiplev.}		1,5		V
		T _j = 150 °C _{chiplev.}		1,5		V
V _{F0}		T _j = 25 °C		1		V
		T _j = 150 °C		0,9		V
r _F		T _j = 25 °C		10		mΩ
		T _j = 150 °C		12		mΩ
I _{RRM}	I _F = 50 A	T _j = 150 °C				A
Q _{rr}						μC
E _{rr}	V _R = 300V			1,07		mJ
R _{th(j-s)D}	per diode			1,7		K/W
Freewheeling Diode (Neutral Clampo diode)						
V _F = V _{EC}	I _{Fnom} = 50 A; V _{GE} = 0 V	T _j = 25 °C _{chiplev.}		1,5		V
		T _j = 150 °C _{chiplev.}		1,5		V
V _{F0}		T _j = 25 °C		1		V
		T _j = 150 °C		0,9		V
r _F		T _j = 25 °C		10		V
		T _j = 150 °C		12		V
I _{RRM}	I _F = 50 A	T _j = 150 °C		40		A
Q _{rr}	di/dt = -2670 A/μs			2,2		μC
E _{rr}	V _R =300V			1,07		mJ
R _{th(j-s)FD}	per diode			1,7		K/W
M _s	to heat sink		2,25		2,5	Nm
w				30		g

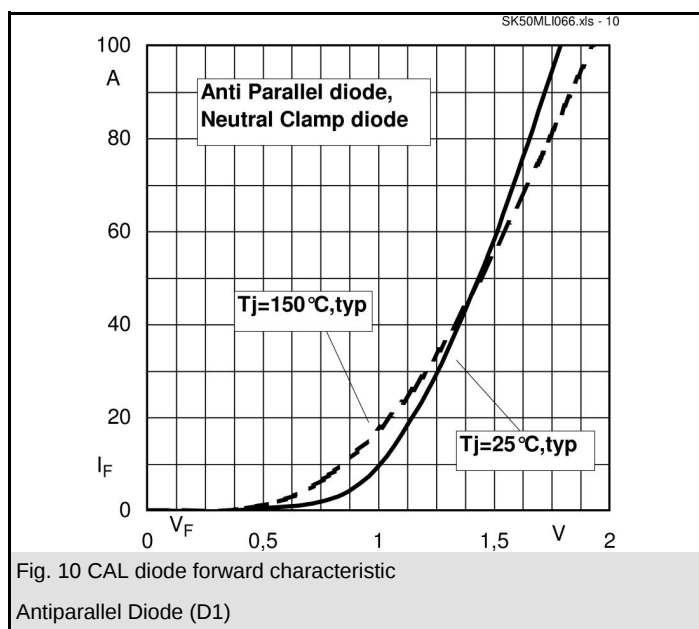
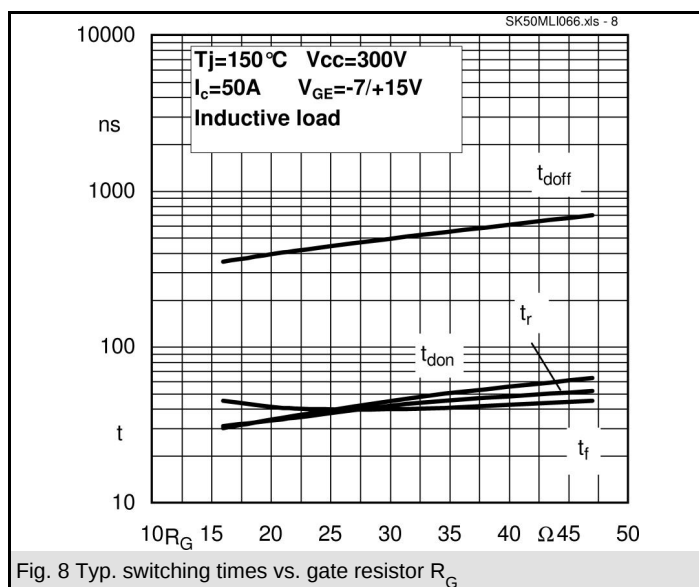
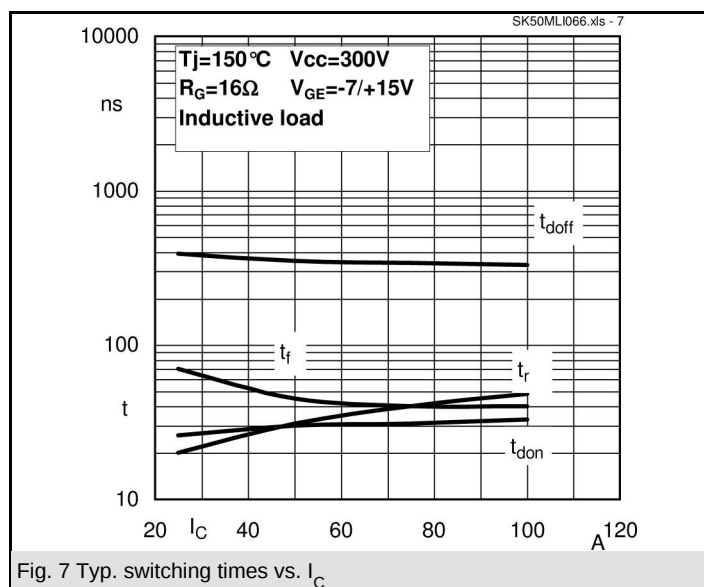
This is an electrostatic discharge sensitive device (ESDS), international standard IEC 60747-1, Chapter IX.

* The specifications of our components may not be considered as an assurance of component characteristics. Components have to be tested for the respective application. Adjustments may be necessary. The use of SEMIKRON products in life support appliances and systems is subject to prior specification and written approval by SEMIKRON. We therefore strongly recommend prior consultation of our personal.



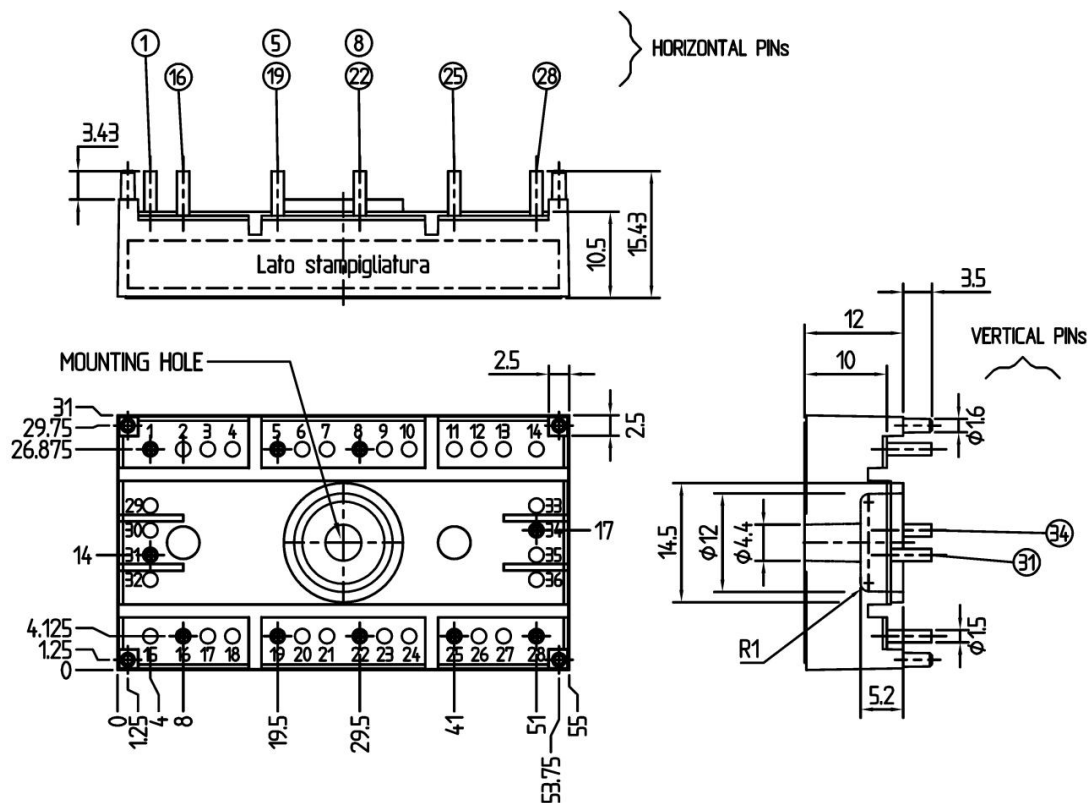
MLI



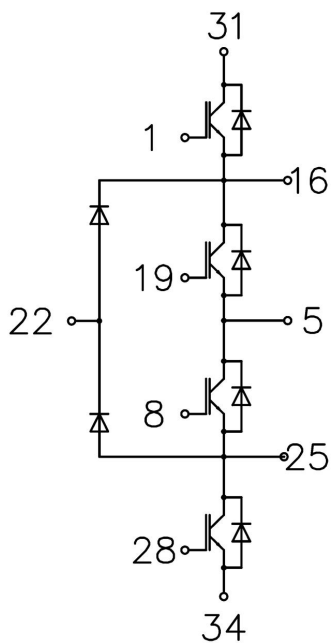


UL recognized

file no. E 63 532



Case T 76 (Suggested hole diameter, in the PCB, for solder pins and plastic mounting pins: 2mm)



Case T 76

MLI